CLAIM AMENDMENTS

This listing of claims will replace all prior versions, and listings, of claims in the

application:

1. (Currently Amended) An apparatus, comprising:

a semiconductor material;

an optical path through the semiconductor material, the optical path optically coupled

to receive an optical beam, the optical beam including one or more wavelengths; and

a nonlinearly chirped Bragg grating disposed in the semiconductor material, the

optical path including the nonlinearly chirped Bragg grating to substantially reduce

chromatic dispersion in the optical beam, the nonlinearly chirped Bragg grating including

regions of silicon and polysilicon disposed in the semiconductor material along the optical

path to provide a plurality of perturbations of a refractive index along the optical path.

2. (Cancelled)

3. (Currently Amended) The apparatus of claim [[2]]1 wherein the plurality of

perturbations of the refractive index are provided with regions of silicon and polysilicon are

disposed in the semiconductor material with a nonlinear periodicity along the optical path.

4. (Original) The apparatus of claim 3 further comprising an adjustable heater

disposed proximate to the nonlinearly chirped Bragg grating to adjust a temperature along the

nonlinearly chirped Bragg grating, wherein an effective index of refraction along the optical

path is responsive to the temperature along the nonlinearly chirped Bragg grating.

Attorney Docket No.: 42P12966 Application No.: 10/004,030 Examiner: Sanghavi, Hemang Art Unit: 2874 5. (Currently Amended) The apparatus of claim [[2]]1 wherein the plurality of perturbations of the refractive index are provided with periodic regions of silicon and polysilicon are periodically disposed in the semiconductor material along the optical path, the apparatus further including a plurality of adjustable heaters disposed proximate to the nonlinearly chirped Bragg grating to adjust a nonlinear temperature gradient in the semiconductor material along the optical path, wherein an effective index of refraction along the optical path is responsive to the nonlinear temperature gradient along the nonlinearly chirped Bragg grating.

6. - 9. (Cancelled)

- 10. (Original) The apparatus of claim 1 further comprising a waveguide disposed in the semiconductor material, the waveguide including the optical path and the nonlinearly chirped Bragg grating.
- 11. (Original) The apparatus of claim 10 wherein the waveguide comprises a rib waveguide disposed in the semiconductor material.
- 12. (Original) The apparatus of claim 1 wherein the optical beam includes said one or more optical channels centered in wavelength bands located at approximately 1310 or 1550 nanometers.

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13. (Currently Amended) A method, comprising:

directing an optical beam through a semiconductor material and to a nonlinearly

chirped Bragg grating disposed in the semiconductor material;

reflecting portions of the optical beam matching a Bragg condition of the nonlinearly

chirped Bragg grating to provide a first chromatic dispersion to the optical beam; and

adjusting the Bragg condition of the nonlinearly chirped Bragg grating to adjust the

first chromatic dispersion provided to the optical beam, the Bragg condition adjusted by

adjusting a temperature of the nonlinearly chirped Bragg grating.

14. (Currently Amended) The method of claim 13 further comprising substantially

negating effects of a second chromatic dispersion introduced to the optical beam, wherein

said first chromatic dispersion is of opposite sign and substantially equal to said second

chromatic dispersion, said negating effects of said second chromatic dispersion introduced to

the optical beam comprising said reflecting portions of the optical beam matching the Bragg

condition of the-sampled nonlinearly chirped Bragg grating.

15. (Currently Amended) The method of claim 13 wherein said adjusting the Bragg

condition of the nonlinearly chirped Bragg grating comprises adjusting an effective refractive

index in the semiconductor material along an optical path of the sampled nonlinearly chirped

Bragg grating.

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17. (Currently Amended) The method of claim [[16]]13 wherein said adjusting the

temperature of the semiconductor material including the nonlinearly chirped Bragg grating

includes adjusting the temperature of the semiconductor material to have a nonlinear

temperature gradient along the optical path of the sampled nonlinearly chirped Bragg grating.

18. (Currently Amended) The method of claim [[16]]13 wherein said adjusting the

temperature of the semiconductor material including the nonlinearly chirped Bragg grating

includes adjusting the temperature of the semiconductor material to have a uniform

temperature along the optical path of the sampled nonlinearly chirped Bragg grating, the

nonlinearly chirped Bragg grating including regions of silicon and polysilicon disposed in the

semiconductor material with nonlinear periodicity along the optical path of the sampled

nonlinearly chirped Bragg grating.

19. - 21. (Cancelled)

22. (Original) The method of claim 14 wherein the optical beam includes a plurality

wavelengths, wherein said negating the effects of the second chromatic dispersion introduced

to the optical beam comprises negating the effects of the second chromatic dispersion

introduced to each of the plurality of wavelengths included in the optical beam.

Attorney Docket No.: 42P12966 Application No.: 10/004,030 Examiner: Sanghavi, Hemang Art Unit: 2874 wavelengths, the method further comprising selecting at least one of the plurality of wavelengths to negate the effects of the second chromatic dispersion introduced to the

23. (Original) The method of claim 13 wherein the optical beam includes a plurality

selected wavelength included in the optical beam, wherein the adjusting of the Bragg

condition of the nonlinearly chirped Bragg grating is in response to the selected wavelength

included in the optical beam.

24. (Original) The method of claim 14 wherein the effects of the second chromatic

dispersion in the optical beam are introduced prior to said directing the optical beam through

the semiconductor material and to the nonlinearly chirped Bragg grating disposed in the

semiconductor material.

25. (Original) The method of claim 14 wherein the effects of the second chromatic

dispersion in the optical beam are introduced after said directing the optical beam through the

semiconductor material and to the nonlinearly chirped Bragg grating disposed in the

semiconductor material.

26. (Currently Amended) A system, comprising:

a first optical device to transmit an optical beam;

a second optical device optically coupled to receive the optical beam from the first

optical device; and

a tunable dispersion compensation device optically coupled between the first and

second optical devices, the optical beam directed from the first optical device through an

optical fiber and to the tunable chromatic dispersion compensation device to the second

optical device, the tunable dispersion compensation device including:

a semiconductor material;

an optical path through the semiconductor material, the optical path optically

coupled to receive the optical beam; and

a nonlinearly chirped Bragg grating including regions of silicon and

polysilicon disposed in the semiconductor material along the optical path, the

nonlinearly chirped Bragg grating having a tunable Bragg condition, the nonlinearly

chirped Bragg grating optically coupled to reflect the optical beam with reduced

chromatic dispersion in the reflected optical beam.

27. (Currently Amended) The system of claim 26 wherein the nonlinearly chirped

Bragg grating includes regions of silicon and polysilicon are disposed in the semiconductor

material with a nonlinear periodicity along the optical path.

28. (Cancelled)

29. (Currently Amended) A system, comprising: The system of claim 28 wherein the

tunable dispersion compensation device includes

a first optical device to transmit an optical beam;

a second optical device optically coupled to receive the optical beam from the first

optical device; and

a tunable dispersion compensation device optically coupled between the first and second optical devices, the optical beam directed from the first optical device through an optical fiber and to the tunable chromatic dispersion compensation device to the second optical device, the tunable dispersion compensation device including:

a semiconductor material;

an optical path through the semiconductor material, the optical path optically coupled to receive the optical beam; and

a plurality of charge modulated regions disposed in the semiconductor material along the optical path, the plurality of charge modulated regions provided with a plurality of insulated electrodes distributed along the optical path to form a nonlinearly chirped Bragg grating having a tunable Bragg condition, the nonlinearly chirped Bragg grating optically coupled to reflect the optical beam with reduced chromatic dispersion in the reflected optical beam.

- 30. (Original) The system of claim 29 wherein adjustable voltages are coupled across the plurality of insulated electrodes with a nonlinear voltage gradient across the plurality of insulated electrodes.
- 31. (Original) The system of claim 29 wherein adjustable voltages are coupled across the plurality of insulated electrodes and wherein the plurality of insulated electrodes are distributed in the semiconductor material along the optical path with nonlinear periodicity.

Attorney Docket No.: 42P12966 Examiner: Sanghavi, Hemang 8 Art Unit: 2874 32. (New) An apparatus, comprising:

a semiconductor material;

an optical path through the semiconductor material, the optical path optically coupled

to receive an optical beam, the optical beam including one or more wavelengths; and

a nonlinearly chirped Bragg grating disposed in the semiconductor material, the

optical path including the nonlinearly chirped Bragg grating to substantially reduce

chromatic dispersion in the optical beam, the nonlinearly chirped Bragg grating including a

plurality of charge-modulated regions disposed in the semiconductor material along the

optical path to provide a plurality of perturbations of a refractive index along the optical path.

33. (New) The apparatus of claim 32 wherein the plurality of charge modulated

regions are provided with a plurality of insulated electrodes distributed along the optical path.

34. (New) The apparatus of claim 33 wherein adjustable voltages are coupled across

the plurality of insulated electrodes with a nonlinear voltage gradient across the plurality of

insulated electrodes.

35. (New) The apparatus of claim 33 wherein an effective index of refraction along

the optical path is responsive to adjustable voltages coupled across the plurality of insulated

electrodes.

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36. (New) The apparatus of claim 33 wherein spacing between the plurality of insulated electrodes in the semiconductor material along the optical path has nonlinear periodicity.

37. (New) A method, comprising:

directing an optical beam through a semiconductor material and to a nonlinearly chirped Bragg grating disposed in the semiconductor material;

reflecting portions of the optical beam matching a Bragg condition of the nonlinearly chirped Bragg grating to provide a first chromatic dispersion to the optical beam; and

adjusting the Bragg condition of the nonlinearly chirped Bragg grating to adjust the first chromatic dispersion provided to the optical beam, the Bragg condition adjusted by adjusting a concentration of charge in each of a plurality of charge modulated regions disposed in the semiconductor material along an optical path.

- 38. (New) The method of claim 37 wherein the plurality of charge modulated regions are provided with a plurality of insulated electrodes distributed along the optical path.
- 39. (New) The method of claim 38 wherein said adjusting the Bragg condition of the nonlinearly chirped Bragg grating includes adjusting an effective refractive index in the semiconductor material along the optical path of the nonlinearly chirped Bragg grating.
- 40. (New) The method of claim 39 wherein said adjusting the concentration of charge in each of the plurality of charge modulated regions in the semiconductor material

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along the optical path includes coupling adjustable voltages across the plurality of insulated

electrodes with a nonlinear voltage gradient across the plurality of insulated electrodes.

41. (New) The method of claim 39 wherein said adjusting the concentration of

charge in each of the plurality of charge modulated regions in the semiconductor material

along the optical path includes coupling adjustable voltages across the plurality of insulated

electrodes with a uniform voltage across the plurality of insulated electrodes, the plurality of

insulated electrodes distributed in the semiconductor material along the optical path with

nonlinear periodicity.